

November 2013

# FQPF16N15

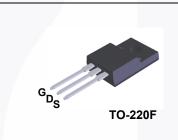
# N-Channel QFET<sup>®</sup> MOSFET 150 V, 11.6 A, 160 m $\Omega$

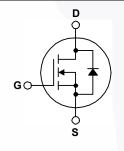
## Description

This N-Channel enhancement mode power MOSFET is produced using Fairchild Semiconductor's proprietary planar stripe and DMOS technology. This advanced MOSFET technology has been especially tailored to reduce on-state resistance, and to provide superior switching performance and high avalanche energy strength. These devices are suitable for switched mode power supplies, audio amplifier, DC motor control, and variable switching power applications.

### Features

- 11.6 A, 150 V,  $R_{DS(on)}$  = 160 m $\Omega$  (Max.) @  $V_{GS}$  = 10 V,  $I_D$  = 5.8 A
- Low Gate Charge (Typ. 23 nC)
- Low Crss (Typ. 30 pF)
- 100% Avalanche Tested
- 175°C Maximum Junction Temperature Rating





## Absolute Maximum Ratings T<sub>c</sub> = 25°C unless otherwise noted

Symbol	Parameter	FQPF16N15	Unit V
V <sub>DSS</sub>	Drain-Source Voltage	150	
I <sub>D</sub>	Drain Current - Continuous (T <sub>C</sub> = 25°C)	11.6	Α
	- Continuous (T <sub>C</sub> = 100°C)	8.2	Α
I <sub>DM</sub>	Drain Current - Pulsed (Note 1)	46.4	Α
V <sub>GSS</sub>	Gate-Source Voltage	± 25	V
E <sub>AS</sub>	Single Pulsed Avalanche Energy (Note 2)	230	mJ
I <sub>AR</sub>	Avalanche Current (Note 1)	11.6	Α
E <sub>AR</sub>	Repetitive Avalanche Energy (Note 1)	5.3	mJ
dv/dt	Peak Diode Recovery dv/dt (Note 3)	6.0	V/ns
PD	Power Dissipation ( $T_C = 25^{\circ}C$ )		W
	- Derate Above 25°C	0.36	W/°C
T <sub>J</sub> , T <sub>STG</sub>	Operating and Storage Temperature Range	-55 to +175	°C
ΤL	Maximum Lead Temperature for Soldering, 1/8" from Case for 5 seconds	300	°C

## **Thermal Characteristics**

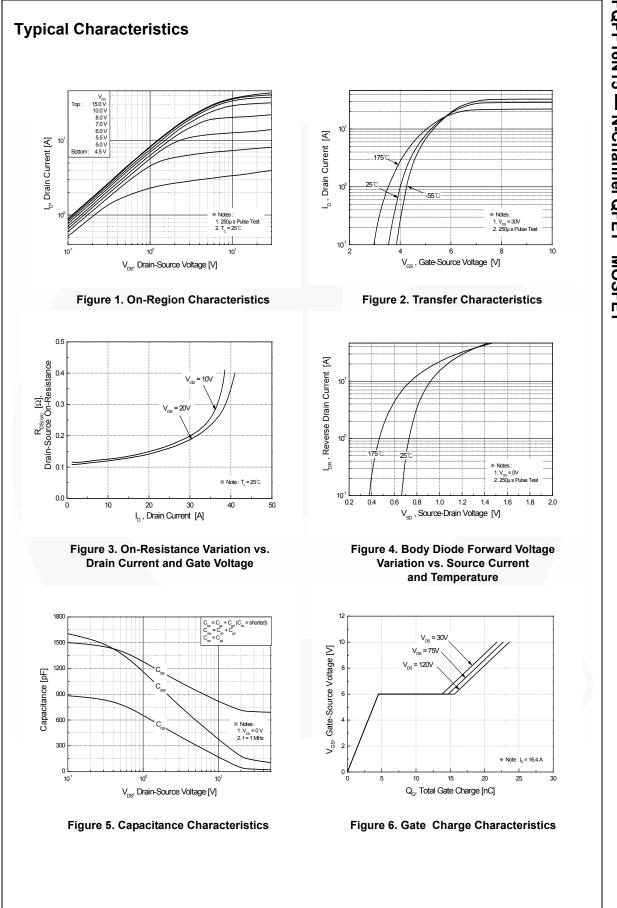
Symbol	Parameter	FQPF16N15	Unit	
$R_{ extsf{ heta}JC}$	Thermal Resistance, Junction-to-Case, Max.	2.78	°C/W	
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction-to-Ambient, Max.	62.5	C/W	

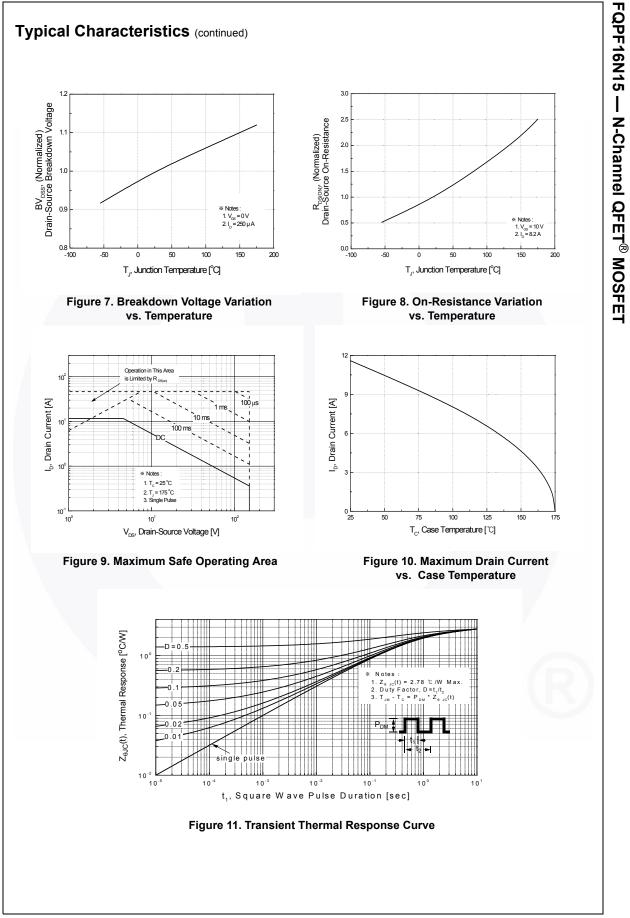
Part Nu	Part NumberTop MarkPackageFQPF16N15FQPF16N15TO-220F		Package	Packing Method Reel Size		Tape Width		Quantity	
FQPF1			Tube N/A		N/A		50 units		
lectri	cal C	haracteristics	T <sub>C</sub> = 25°C	unless otherwise noted.					
Symbol		Parameter		Test Condit	ions	Min.	Тур.	Max.	Unit
Off Ch	aracto	ristics							
BV <sub>DSS</sub>	aracteristics Drain-Source Breakdown Voltage		oltage	V <sub>GS</sub> = 0 V, I <sub>D</sub> = 250 μA		150			V
ABV <sub>DSS</sub>			0			100			v
$\Delta T_{J}$	Breakdown Voltage Temperature Coefficient		alure	$I_D$ = 250 $\mu$ A, Referenced to 25°C			0.17		V/°C
DSS	Zero Gate Voltage Drain Current		rront	V <sub>DS</sub> = 150 V, V <sub>GS</sub> = 0 V				1	μA
			Irrent	V <sub>DS</sub> = 120 V, T <sub>C</sub> = 150°C				10	μA
GSSF	Gate-	Body Leakage Currer	nt, Forward	V <sub>GS</sub> = 25 V, V <sub>DS</sub> = 0 V				100	nA
GSSR	Gate-I	Body Leakage Currer	nt, Reverse	$V_{GS}$ = -25 V, $V_{DS}$ = 0	V			-100	nA
		inting							
V <sub>GS(th)</sub>	aracteristics Gate Threshold Voltage		V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA		2.0		4.0	V	
R <sub>DS(on)</sub>		Static Drain-Source On-Resistance		$V_{GS} = 10 \text{ V}, \text{ I}_{D} = 5.8 \text{ A}$		2.0	0.12	4.0	v
-DS(0II)							3	0.16	Ω
FS	Forward Transconductance			$V_{DS}$ = 40 V, I <sub>D</sub> = 5.8	A		8.3		S
D	ia Cha	ve ete vietie e							
Dynam C <sub>iss</sub>	1	Tracteristics					700	910	pF
Soss				$V_{DS} = 25 V, V_{GS} = 0 V,$			145	190	pF
Crss		Output Capacitance Reverse Transfer Capacitance		f = 1.0 MHz			30	40	pF
-155	1.070		100					10	p.
		aracteristics							
d(on)		On Delay Time		V <sub>DD</sub> = 75 V, I <sub>D</sub> = 16.4 A,			11	30	ns
r		On Rise Time		R <sub>G</sub> = 25 Ω	-		115	240	ns
d(off)		Off Delay Time			(Note 4)		50	110	ns
f		Off Fall Time		(Note 4)			80	170	ns
2 <sub>g</sub>		Gate Charge		$V_{DS}$ = 120 V, I <sub>D</sub> = 16.4 A, $V_{GS}$ = 10 V (Note 4)			23	30	nC
2 <sub>gs</sub>		Source Charge					4.5		nC
ຊ <sub>gd</sub>	Gate-L	Drain Charge					11		nC
Drain_9	Sourco	Diodo Charact	vrietice an	d Maximum Rati	inge				
	-	um Continuous Drair			iiys			11.6	Δ
S		num Pulsed Drain-So						46.4	A
sм / <sub>SD</sub>		Source Diode Forwar	r					1.5	A V
r SD		se Recovery Time	u voliage	$V_{GS} = 0 V, I_S = 11.6 A$ $V_{GS} = 0 V, I_S = 16.4 A,$			 85	_	
տ Չո		se Recovery Time		$V_{GS} = 0 V, I_S = 16.4 A,$ dI <sub>F</sub> / dt = 100 A/µs			0.35		ns μC

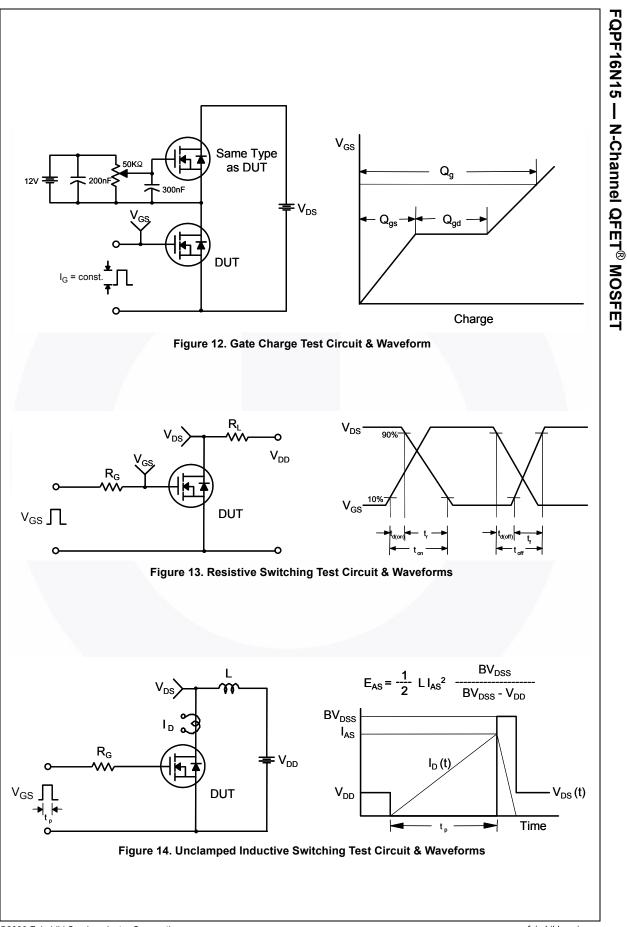
 $\begin{array}{l} 2. \ L=2.85 \ \text{mH}, \ I_{AS}=11.6 \ \text{A}, \ V_{DD}=25 \ \text{V}, \ \text{R}_{G}=25 \ \Omega, \ \text{starting} \ \ \text{T}_{J}=25^{\circ}\text{C}. \\ 3. \ I_{SD}\leq11.6 \ \text{A}, \ \text{di/dt}\leq300 \ \text{A/}\mu\text{s}, \ \text{V}_{DD}\leq8V_{DSS}, \ \text{starting} \ \ \text{T}_{J}=25^{\circ}\text{C}. \end{array}$ 

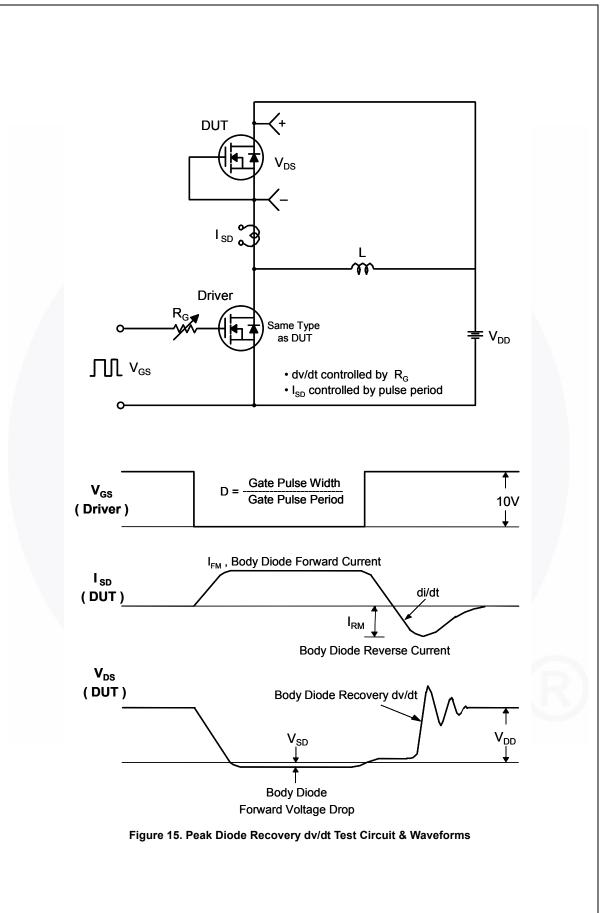
4. Essentially independent of operating temperature.

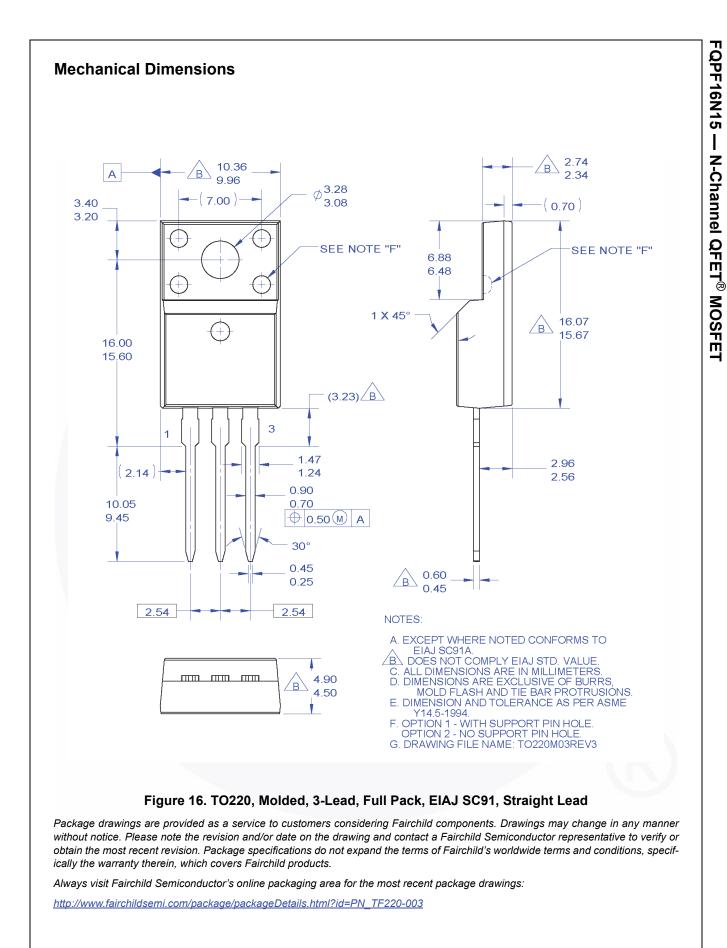
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